NSVR201MX

Advance Information Schottky Barrier Diode for Mixer and Detector

Automotive Schottky Barrier Diode designed for compact and efficient designs. AEC-Q101 qualified Schottky Barrier Diode and PPAP capable suitable for automotive applications.

Features

- Small Interterminal Capacitance
- Less Parasitic Components
- Small Forward Voltage
- Small-sized Package
- Pb-Free, Halogen Free and RoHS compliance
- AEC-Q101 qualified and PPAP capable

Typical Applications

- Microwave and Milliwave Mixer
- Microwave and Milliwave Detector

SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS at Ta = 25°C (Note 1)

Parameter	Symbol	Value	Unit
Reverse Voltage	VR	2	V
Forward Current	١F	50	mA
Operating Junction and Storage Temperature	T _{J,} T _{stg}	-55 to +150	°C

Note 1 : Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



ON Semiconductor®

www.onsemi.com

2V, 50mA C=0.25pF typ. Shottky Barrier Diode



X2DFN2 1.0x0.6, 0.65P

ELECTRICAL CONNECTION



MARKING DIAGRAM



F = Specific Device Code

M = Date Code

= Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet

This document contains information on a new product. Specifications and information herein are subject to change without notice.

NSVR201MX

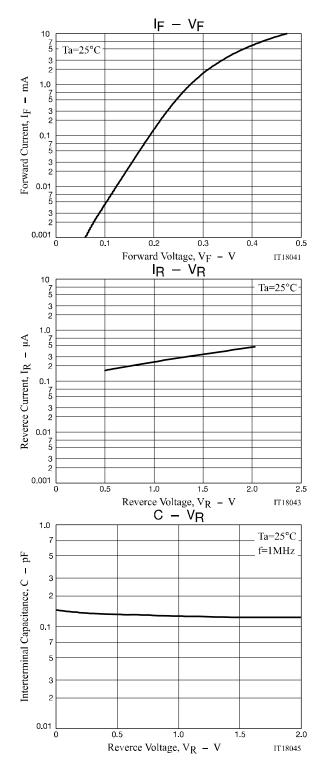
Parameter	Symbol					
		Conditions	min	typ	max	Unit
Reverse Voltage	V _R	I _R = 10μA	2			V
Forward Voltage	VF	I _F = 1mA			320	mA
Series Resistance	RS	I _F = 10mA		14	18	Ω
Interterminal Capacitance	С	V _R = 0V, f = 1MHz		0.15	0.20	pF

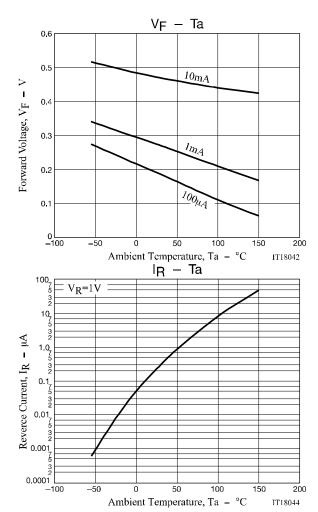
ELECTRICAL CHARACTERISTICS at Ta = 25°C (Notes 2, 3)

Note 2 : Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Note 3 : Pay attention to handling since it is liable to be affected by static electricity due to the high-frequency process adopted.

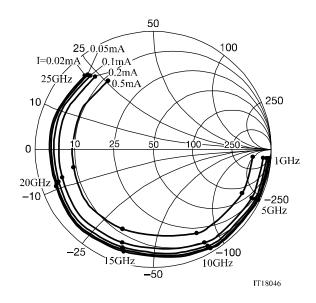
NSVR201MX





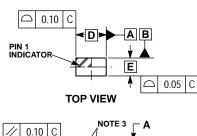
S Parameter (Zo=50Ω)

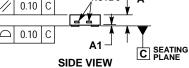
	=()mA	I = 0.0)2mA	=0.0	05mA	I = 0.	.1mA	I = 0.	.2mA	I = 0.	.5mA
Freq[GHz]	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
1	0.964	-4.4	0.988	-4.3	0.978	-4.3	0.963	-4.3	0.933	-4.4	0.845	-4.3
2	0.967	-9.7	0.990	-9.6	0.981	-9.6	0.966	-9.7	0.937	-9.7	0.852	-9.5
3	0.957	-15.2	0.981	-15.1	0.971	-15.2	0.956	-15.2	0.925	-15.4	0.838	-15.7
4	0.956	-20.5	0.980	-20.3	0.970	-20.5	0.956	-20.5	0.925	-20.6	0.840	-20.4
5	0.961	-26.0	0.986	-25.7	0.977	-25.9	0.960	-26.0	0.929	-26.2	0.838	-26.3
6	0.954	-32.3	0.981	-31.9	0.970	-32.1	0.953	-32.3	0.919	-32.5	0.822	-32.5
7	0.943	-39.2	0.969	-38.7	0.959	-39.0	0.942	-39.2	0.909	-39.6	0.814	-40.4
8	0.943	-45.7	0.967	-45.2	0.958	-45.4	0.942	-45.7	0.911	-46.2	0.823	-47.4
9	0.947	-52.8	0.975	-52.2	0.963	-52.5	0.946	-52.8	0.910	-53.3	0.809	-54.2
10	0.940	-60.6	0.968	-59.9	0.957	-60.2	0.938	-60.6	0.902	-61.2	0.799	-62.6
11	0.921	-69.7	0.950	-68.9	0.939	-69.3	0.919	-69.7	0.883	-70.4	0.777	-72.0
12	0.895	-80.4	0.928	-79.4	0.914	-79.9	0.893	-80.4	0.852	-81.2	0.738	-83.5
13	0.882	-88.8	0.912	-87.7	0.900	-88.2	0.881	-88.8	0.843	-89.6	0.735	267.9
14	0.872	261.9	0.906	263.1	0.893	262.4	0.871	261.9	0.831	261.0	0.715	258.8
15	0.870	252.7	0.900	253.9	0.887	253.2	0.868	252.6	0.830	251.6	0.723	249.0
16	0.874	242.8	0.903	244.1	0.891	243.4	0.873	242.7	0.838	241.6	0.733	238.1
17	0.874	231.6	0.907	233.1	0.894	232.3	0.873	231.6	0.833	230.4	0.720	227.0
18	0.877	220.8	0.911	222.5	0.898	221.6	0.875	220.7	0.833	219.3	0.715	215.4
19	0.860	210.3	0.895	212.1	0.881	211.1	0.859	210.2	0.817	208.7	0.700	204.2
20	0.847	198.7	0.880	200.7	0.866	199.6	0.845	198.7	0.806	197.2	0.692	192.7
21	0.841	185.5	0.875	187.4	0.860	186.4	0.840	185.4	0.800	184.0	0.687	179.7
22	0.847	171.1	0.883	173.3	0.868	172.2	0.846	171.1	0.803	169.3	0.683	164.0
23	0.845	157.2	0.877	159.6	0.864	158.3	0.843	157.1	0.804	155.1	0.696	149.5
24	0.822	142.0	0.854	144.5	0.840	143.2	0.821	142.1	0.782	140.1	0.680	134.7
25	0.823	130.3	0.852	132.6	0.840	131.4	0.822	130.3	0.788	128.6	0.695	123.3
26	0.833	118.3	0.863	120.7	0.850	119.5	0.832	118.2	0.797	116.5	0.703	111.1

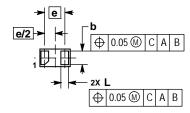


X2DFN2 1.0x0.6, 0.65P

CASE 714AB **ISSUE O**

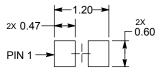






BOTTOM VIEW

RECOMMENDED **SOLDER FOOTPRINT***



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

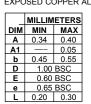
ORDERING INFORMATION

Device	Device Marking		Shipping	
NSVR201MXT5G	F	X2DFN2 1.0×0.6, 0.65P (Pb-Free / Halogen Free)	8,000 / Tape & Reel	

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights or the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products harmless against all claims, costs, damages, and indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and reasonable altorney fees arising out of directly or indirectly any claim of personal injury or death associated with such unintended or expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

- . DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. . CONTROLLING DIMENSION: MILLIMETERS.
- 2 3 EXPOSED COPPER ALLOWED AS SHOWN



GENERIC **MARKING DIAGRAM***



XX = Specific Device Code

- = Date Code Μ
- = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present.